# 5GHz Band SPDT Switch + LNA GaAs MMIC

#### ■ GENERAL DESCRIPTION

The NJG1739K51 is a 5GHz band SPDT switch + low noise amplifier GaAs MMIC designed for wireless LAN front-end applications.

The NJG1739K51 features low current consumption. low insertion loss of transmit path and low noise figure of RX LNA mode.

The NJG1739K51 has ESD protection devices to achieve excellent ESD performances.

A small and ultra-thin package of QFN12-51 is adopted.

#### ■ APPLICATIONS

5GHz Band WLAN front-end application

#### ■ FEATURES

<ul> <li>Operating voltage</li> </ul>	V <sub>DD</sub> =3.6V typ.
<ul> <li>Operating frequency</li> </ul>	freq=4900 to 5900MHz

#### [RX LNA mode]

 Operating current 8mA typ. @V<sub>DD</sub>=3.6V, V<sub>CTL</sub>1=V<sub>CTL</sub>3=3.3V, V<sub>CTL</sub>2=0V Small signal gain 12.0dB typ.

2.5dB typ.

0dBm typ.

- Noise figure
- Input power 1dB compression

#### [RX Bypass mode]

Operating current

Insertion loss

- Input power 1dB compression
- 4µA typ. @V<sub>DD</sub>=3.6V, V<sub>CTL</sub>1=3.3V, V<sub>CTL</sub>2=V<sub>CTL</sub>3=0V 8.5dB typ.

- [TX mode]
  - Insertion loss
  - Input power 0.1dB compression

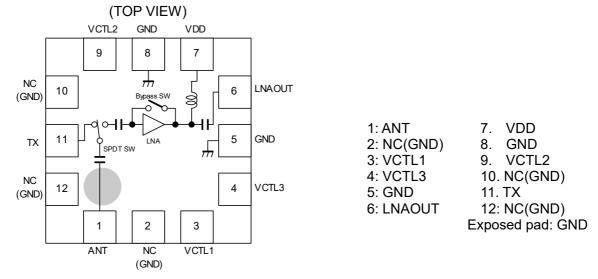
0.5dB typ. +29dBm typ.

+15dBm typ.

Package

QFN12-51 (Package size: 2.0mm x 2.0mm x 0.375mm typ.) RoHS compliant and Halogen Free, MSL1

#### ■ PIN CONFIGURATION



Note: Specifications and description listed in this datasheet are subject to change without notice.

# Nisshinbo Micro Devices Inc.



PACKAGE OUTLINE

NJG1739K51

# TRUTH TABLE

mada	VCTL1	VCTL2	VCTL3			STATE		
mode	(SW RX)	(SW TX)	(LNA)	IDD	LNA	Bypass	RX SW	TX SW
RX LNA	Н	L	Н	I <sub>DD</sub> 1	ON	OFF	ON	OFF
RX Bypass	Н	L	L	I <sub>DD</sub> 2	OFF	ON	ON	OFF
ТХ	L	Н	L	I <sub>DD</sub> 2	OFF	ON	OFF	ON
Sleep	L	L	L	I <sub>DD</sub> 3	OFF	OFF	OFF	OFF

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## ■ ABSOLUTE MAXIMUM RATINGS

				Г <sub>а</sub> =+25°С
PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V <sub>DD</sub>		5.5	V
Control voltage	V <sub>CTL</sub>		5.5	V
Input power 1	P <sub>IN1</sub>	ANT terminal, V <sub>DD</sub> =3.6V, V <sub>CTL</sub> 1=V <sub>CTL</sub> 3=3.3V, V <sub>CTL</sub> 2=0V	+15	dBm
Input power 2	P <sub>IN2</sub>	TX terminal, V <sub>DD</sub> =3.6V, V <sub>CTL</sub> 1=V <sub>CTL</sub> 3=0V, V <sub>CTL</sub> 2=3.3V	+30	dBm
Power dissipation	PD	Four-layer FR4 PCB with through-hole (101.5x114.5mm), T <sub>j</sub> =150°C	1190	mW
Operation temperature	T <sub>opr</sub>		-40 to +85	٥C
Storage temperature	T <sub>stg</sub>		-55 to +150	°C

# ■ ELECTRICAL CHARACTERISTICS 1 (DC Characteristics)

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	-	V <sub>DD</sub> =3.6V, V <sub>CTL</sub> (H)=3.3V, V <sub>C</sub>	<sub>т∟(L)=0</sub>	V, T <sub>a</sub> =+2	25°C, Z	<sub>s</sub> =Ζ <sub>l</sub> =50Ω
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply voltage	V <sub>DD</sub>		3.0	3.6	5.0	V
Control voltage 1(High)	V <sub>CTL</sub> 1(H)		2.8	3.3	5.0	V
Control voltage 2(High)	V <sub>CTL</sub> 2(H)		2.8	3.3	5.0	V
Control voltage 3(High)	V <sub>CTL</sub> 3(H)		2.8	3.3	5.0	V
Control voltage 1(Low)	Vcт∟1(L)		0.0	-	0.4	V
Control voltage 2(Low)	V <sub>CTL</sub> 2(L)		0.0	-	0.4	V
Control voltage 3(Low)	V <sub>CTL</sub> 3(L)		0.0	-	0.4	V
LNA operating current 1 (RX LNA mode)	IDD1	RF OFF, Vctl1=Vctl3=3.3V, Vctl2=0V	-	8	13	mA
LNA operating current 2 (RX Bypass mode)	IDD2	RF OFF, V <sub>CTL</sub> 1=3.3V, V <sub>CTL</sub> 2=V <sub>CTL</sub> 3=0V	-	4	12	μA
LNA operating current 3 (Sleep mode)	IDD3	RF OFF, Vctl1=Vctl2=Vctl3=0.4V	-	4	12	μA
LNA operating current 4 (VCTL OPEN)	Idd4	RF OFF, VcтL1=VcTL2=VcTL3=open	-	4	12	μA
Control current 1	Іст∟1	RF OFF, Vctl1=3.3V, Vctl2=Vctl3=0V	-	5	20	μA
Control current 2	Іст∟2	RF OFF, V <sub>CTL</sub> 2=3.3V, V <sub>CTL</sub> 1=V <sub>CTL</sub> 3=0V	-	5	20	μA
Control current 3	Іст∟З	RF OFF, Vctl3=3.3V, Vctl1=Vctl2=0V	-	5	20	μA

#### ■ ELECTRICAL CHARACTERISTICS 2 (RF Characteristics: RX LNA mode, LNA+SPDT SW) V<sub>DD</sub>=3.6V, V<sub>CTL</sub>1=V<sub>CTL</sub>3=3.3V, V<sub>CTL</sub>2=0V, freq=4900 to 5900MHz,

$T_a$ =+25°C, $Z_s$ = $Z_l$ =50 $\Omega$ , with application circuit
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		$1_{a} - 1_{z} = 1_{z}$		2, With t	appliouti	on on our
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain 1	Gain1	Exclude PCB and connector losses*1	9.0	12.0	14.0	dB
Gain flatness 1	Gflat1	f=4900 to 4980MHz, f=5400 to 5480MHz, f=5820 to 5900MHz	-	-	0.3	dB
Isolation 1	ISL1		-	30	-	dB
Noise figure 1	NF1	Exclude PCB and connector losses*2	-	2.5	3.0	dB
Input power at 1dB compression 1	P-1dB(IN) <b>1</b>		-	0	-	dBm
Input 3rd order Intercept point 1	IIP3_1	f1=freq, f2=freq+100kHz, Pıℕ=-18dBm	-	+9	-	dBm
Outband input 3rd order Intercept point 1	IIP3_OB1	f1=2450MHz, f2=f1+100kHz, Pıℕ=-18dBm	-	+2	-	dBm
ANT port return loss 1	RLi1		-	8.0	-	dB
LNAOUT port return loss 1	RLo1		-	9.0	-	dB
LNA switching time	Tsw1_1	10% V <sub>CTL</sub> to 90% RF	-	250	400	ns
Other switching time	Tsw2_1	10% V <sub>CTL</sub> to 90% RF	-	200	500	ns

\*1) 0.64dB(4900MHz), 0.71dB(5400MHz), 0.79dB(5900MHz)

\*2) 0.32dB(4900MHz), 0.35dB(5400MHz), 0.39dB(5900MHz)

#### ■ ELECTRICAL CHARACTERISTICS 3 (RF Characteristics: RX Bypass mode, Bypass SW+SPDT SW) V<sub>DD</sub>=3.6V, V<sub>CTL</sub>1=3.3V, V<sub>CTL</sub>2=V<sub>CTL</sub>3=0V, freq=4900 to 5900MHz, T<sub>2</sub>=+25°C, Z<sub>2</sub>=Z<sub>1</sub>=50Ω, with application circuit

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PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Insertion loss 2	LOSS2	Exclude PCB and connector losses*3	6.0	8.5	10.5	dB
Input power at 1dB compression 2	P-1dB(IN)2		-	+15	-	dBm
Input 3rd order Intercept point 2	IIP3_2	f1=freq, f2=freq+100kHz, Pıℕ=-10dBm	-	+14	-	dBm
ANT port return loss 2	RLi2		-	7.0	-	dB
LNAOUT port return loss 2	RLo2		-	12.0	-	dB

\*3) 0.64dB(4900MHz), 0.71dB(5400MHz), 0.79dB(5900MHz)

# NJG1739K51

# **ELECTRICAL CHARACTERISTICS 4** (RF Characteristics: TX mode, SPDT SW)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=0V,  $V_{CTL}$ 2=3.3V, freq=4900 to 5900MHz,  $T_a$ =+25°C,  $Z_s$ = $Z_I$ =50 $\Omega$ , with application circuit

		$r_a - 200, z_s$	- <b>Z</b>  -003	2, WIUI C	ipplicati	on on our
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Insertion loss 3	LOSS3	P <sub>IN</sub> =+23dBm, Exclude PCB and connector losses*4	-	0.5	0.8	dB
Input power at 0.1dB compression 3	P-0.1dB(IN)3		-	+29	-	dBm
ANT port return loss 3	RLi3		-	16	-	dB
TX port return loss 3	RLo3		-	20	-	dB

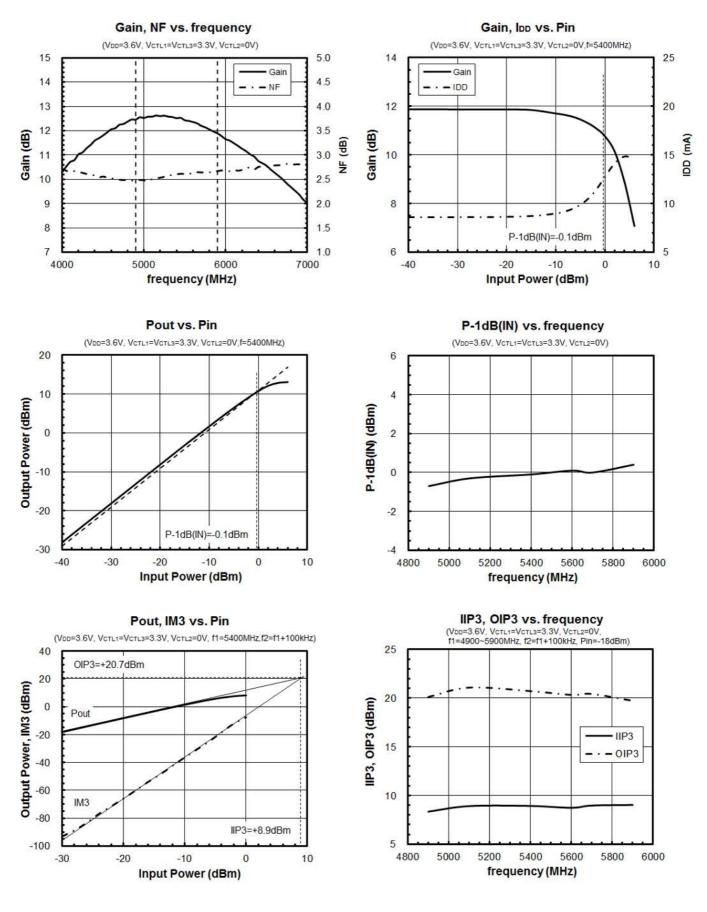
\*4) 0.65dB(4900MHz), 0.73dB(5400MHz), 0.81dB(5900MHz)

#### ■ TERMINAL INFORMATION

Pin No.	SYMBOL	DESCRIPTION
1	ANT	RF transmitting/receiving terminal. No DC blocking capacitor is required for this port because of internal capacitor.
2	NC(GND)	No connected terminal. This terminal is not connected with internal circuit. Please connect to the PCB ground plane.
3	VCTL1	Control signal input terminal. This terminal is set to High-Level (+2.8 to +5.0V) or Low-Level (0 to +0.4V).
4	VCTL3	Control signal input terminal. This terminal is set to High-Level (+2.8 to +5.0V) or Low-Level (0 to +0.4V).
5	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
6	LNAOUT	RF receiving signal output terminal. No DC blocking capacitor is required for this port because of internal output matching circuit including DC blocking capacitor.
7	VDD	Positive voltage supply terminal. The positive voltage (+3.0 to +5.0V) has to be supplied. Please connect a bypass capacitor with GND terminal for excellent RF performance.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
9	VCTL2	Control signal input terminal. This terminal is set to High-Level (+2.8 to +5.0V) or Low-Level (0 to +0.4V).
10	NC(GND)	No connected terminal. This terminal is not connected with internal circuit. Please connect to the PCB ground plane.
11	тх	RF transmitting signal input terminal. DC blocking capacitor is required for this port.
12	NC(GND)	No connected terminal. This terminal is not connected with internal circuit. Please connect to the PCB ground plane.
Exposed Pad	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance, and through holes for GND should be placed near by the pin connection

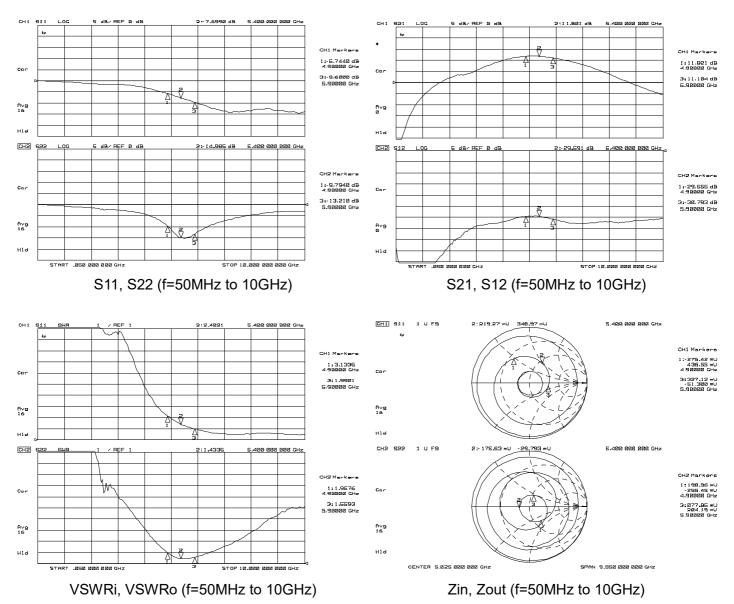
# ELECTRICAL CHARACTERISTICS (RX LNA mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=3.3V,  $V_{CTL}$ 2=0V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 



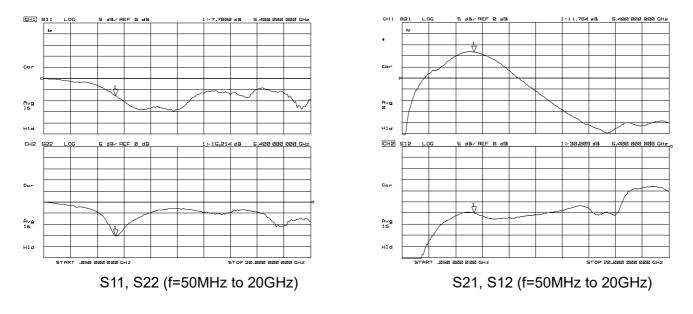
# ELECTRICAL CHARACTERISTICS (RX LNA mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=3.3V,  $V_{CTL}$ 2=0V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 

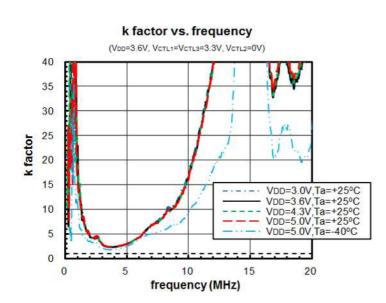


# ■ ELECTRICAL CHARACTERISTICS (RX LNA mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=3.3V,  $V_{CTL}$ 2=0V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 

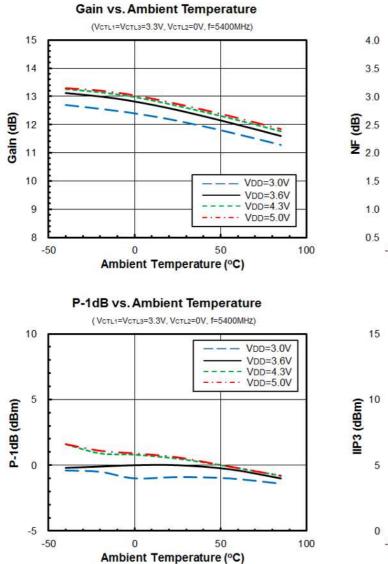


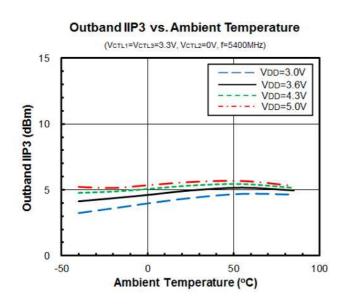
■ ELECTRICAL CHARACTERISTICS (RX LNA mode) V<sub>CTL</sub>1=V<sub>CTL</sub>3=3.3V, V<sub>CTL</sub>2=0V, Z<sub>s</sub>=Z<sub>I</sub>=50Ω

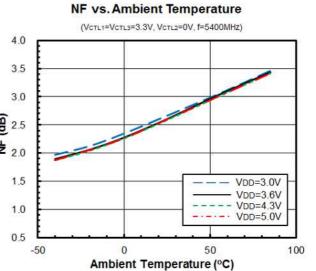


# ■ ELECTRICAL CHARACTERISTICS (RX LNA mode)

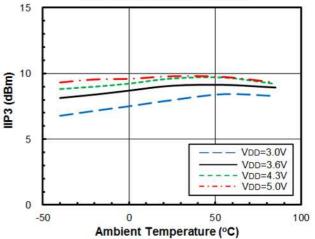
 $V_{CTL}$ 1= $V_{CTL}$ 3=3.3V,  $V_{CTL}$ 2=0V,  $Z_s$ = $Z_l$ =50 $\Omega$ 





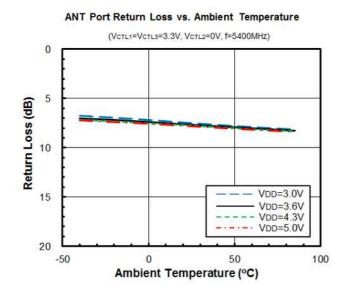


IIP3 vs. Ambient Temperature (VcrL1=VcrL3=3.3V, VcrL2=0V, f=5400MHz)

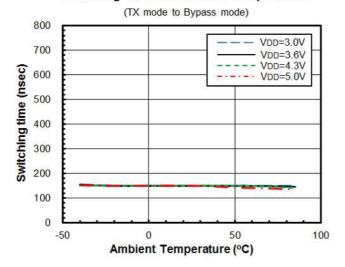


# ■ ELECTRICAL CHARACTERISTICS (RX LNA mode)

V<sub>CTL</sub>1=V<sub>CTL</sub>3=3.3V, V<sub>CTL</sub>2=0V, Z<sub>s</sub>=Z<sub>I</sub>=50Ω



Switching Time vs. Ambient Temperature

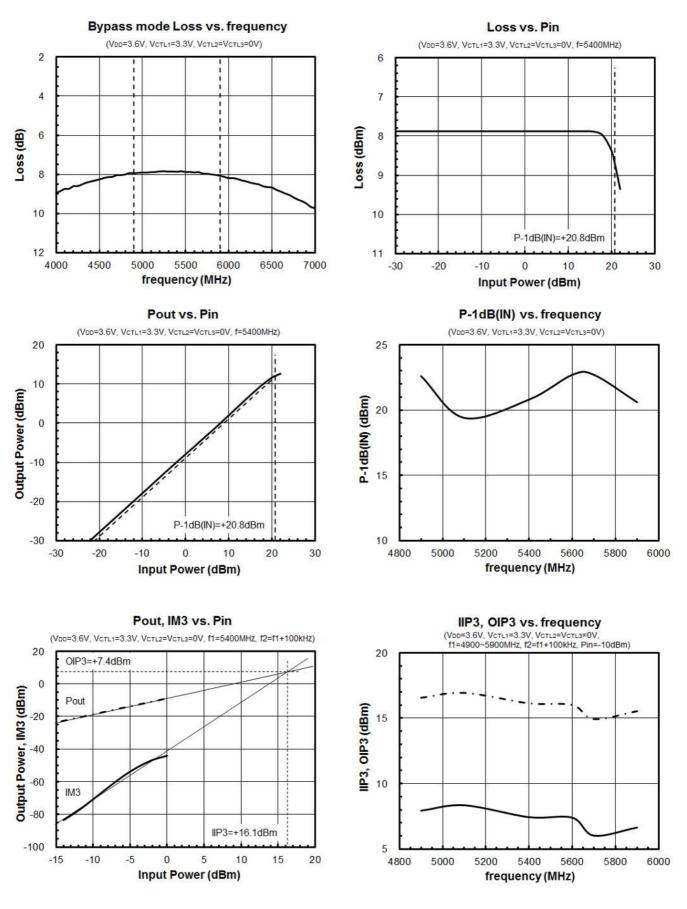


(VCTL1=VCTL3=3.3V, VCTL2=0V, f=5400MHZ) 0 VDD=3.0V VDD=3.6V VDD=4.3V VDD=5.0V 5 . . . Return Loss (dB) 10 15 20 0 50 100 -50 Ambient Temperature (°C)

LNAOUT Port Return Loss vs. Ambient Temperature

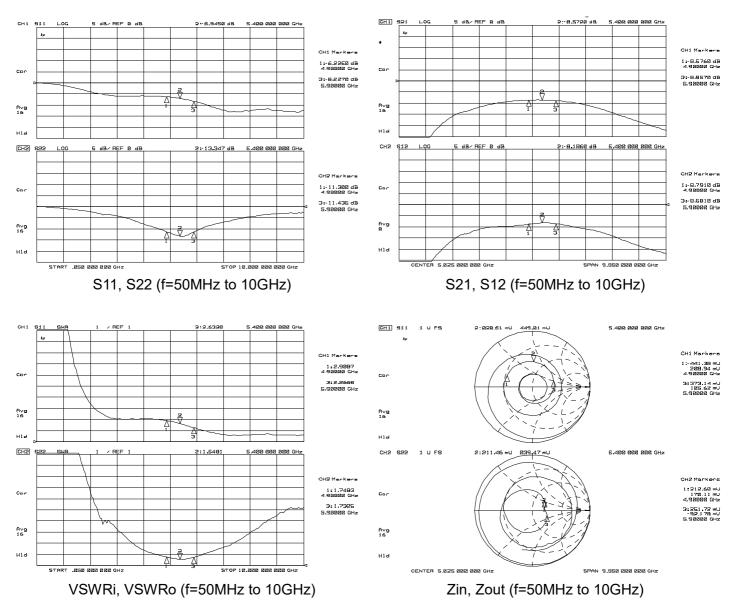
# ■ ELECTRICAL CHARACTERISTICS (RX Bypass mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1=3.3V,  $V_{CTL}$ 2= $V_{CTL}$ 3=0V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 



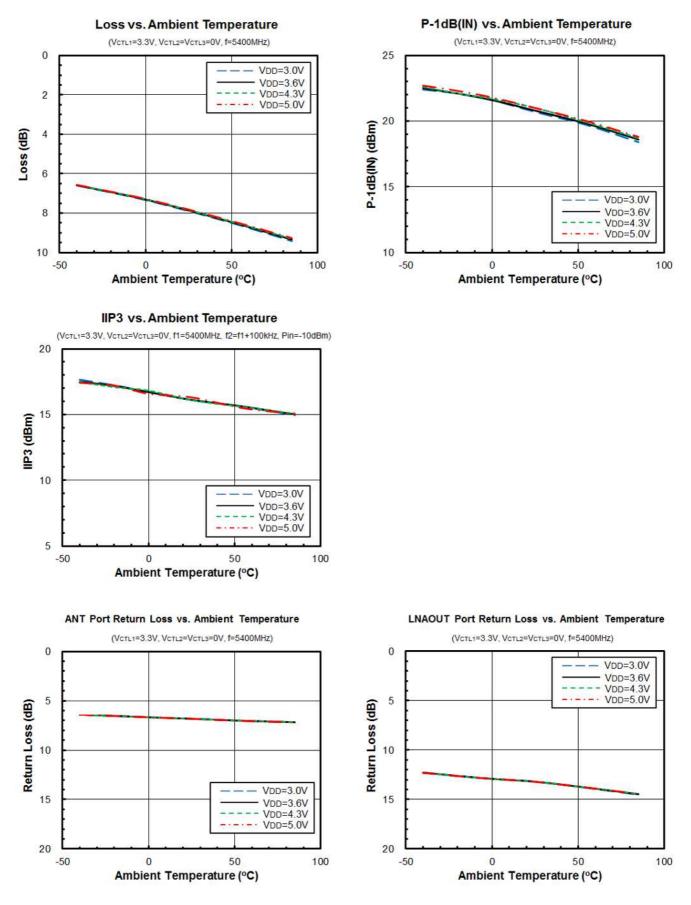
# ■ ELECTRICAL CHARACTERISTICS (RX Bypass mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1=3.3V,  $V_{CTL}$ 2= $V_{CTL}$ 3=0V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 



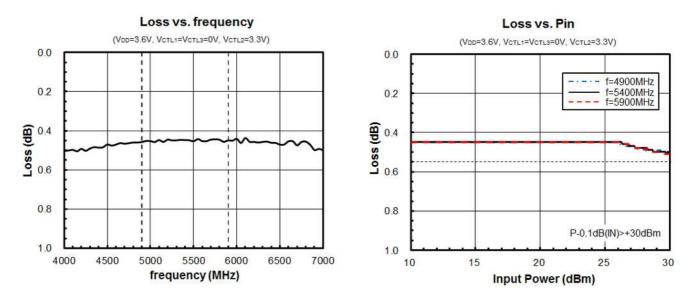
## ■ ELECTRICAL CHARACTERISTICS (RX Bypass mode)

 $V_{CTL}$ 1=3.3V,  $V_{CTL}$ 2= $V_{CTL}$ 3=0V,  $Z_s$ = $Z_l$ =50 $\Omega$ 



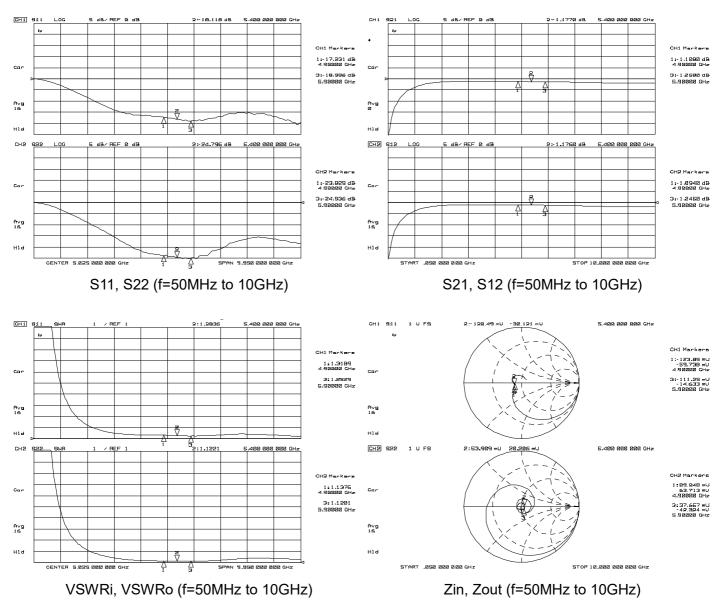
# ■ ELECTRICAL CHARACTERISTICS (TX mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=0V,  $V_{CTL}$ 2=3.3V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 



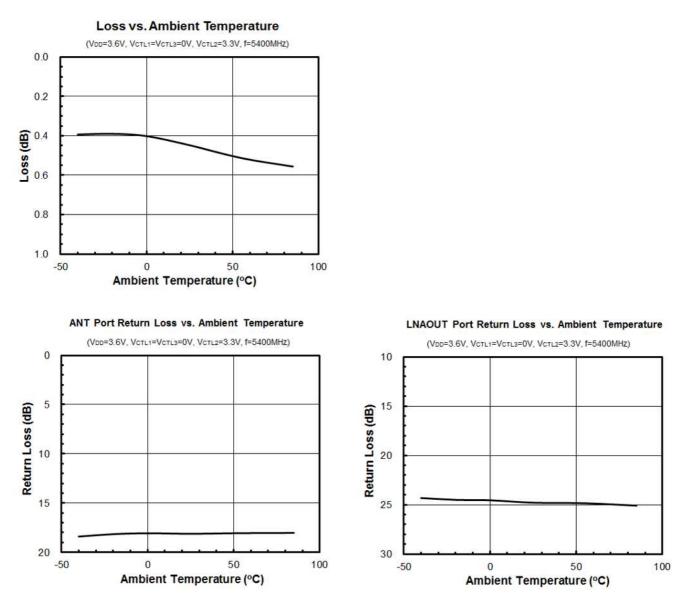
# ■ ELECTRICAL CHARACTERISTICS (TX mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=0V,  $V_{CTL}$ 2=3.3V,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ 

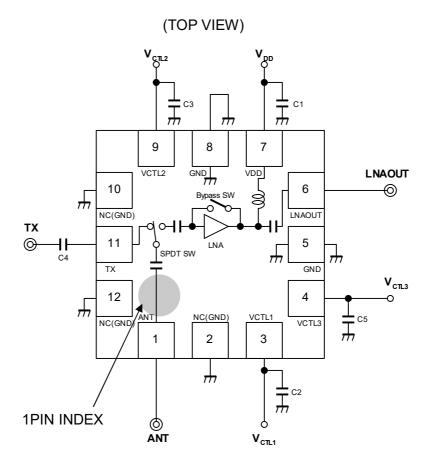


### ELECTRICAL CHARACTERISTICS (TX mode)

 $V_{DD}$ =3.6V,  $V_{CTL}$ 1= $V_{CTL}$ 3=0V,  $V_{CTL}$ 2=3.3V,  $Z_s$ = $Z_l$ =50 $\Omega$ 

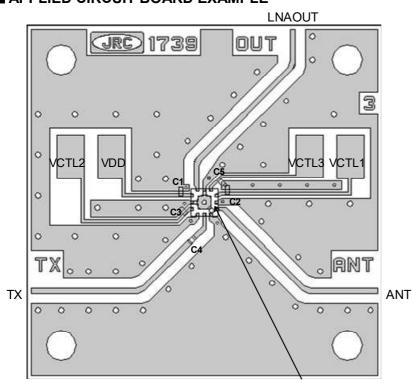


# ■ APPLICATION CIRCUIT

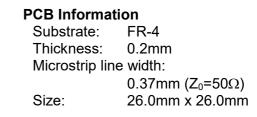


#### PARTS LIST

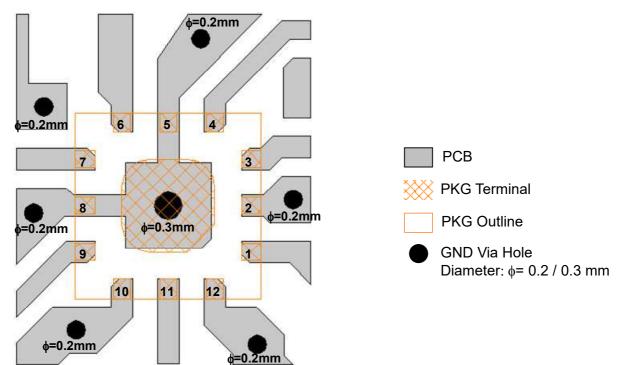
ID No.	Value	Notes
C1	0.1µF	
C2, C3, C5	10pF	Murata MFG (GRM03 series)
C4	27pF	



#### APPLIED CIRCUIT BOARD EXAMPLE



<PCB LAYOUT GUIDELINE>



1pin Index

#### PRECAUTIONS

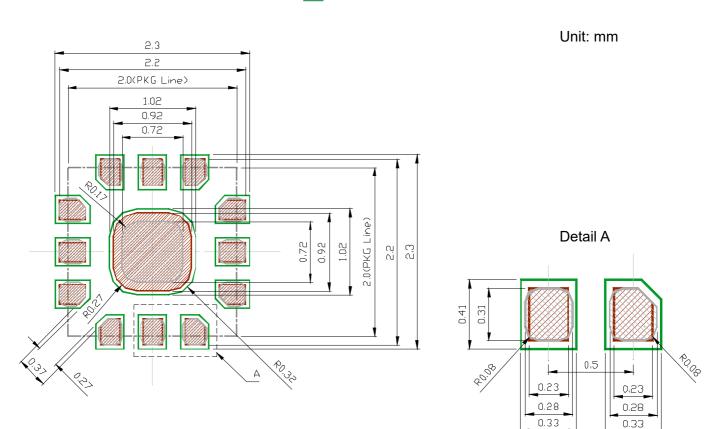
- [1] All external parts should be placed as close as possible to the IC.
- [2] For avoiding the degradation of RF performance, the bypass capacitor (C1) should be placed as close as possible to VDD terminal.
- [3] For good RF performance, the ground terminals must be placed possibly close to ground plane of substrate, and through holes for GND should be placed near by the pin connection.

# ■ RECOMMENDED FOOTPRINT PATTERN (QFN12-51 PACKAGE Reference)

PKG: 2.0mm x 2.0mm Pin pitch: 0.5mm 💹 : Land

 $\odot$  : Mask (Open area) \*Metal mask thickness: 100 $\mu$ m

: Resist (Open area)



#### ■ NOISE FIGURE MEASUREMENT BLOCK DIAGRAM

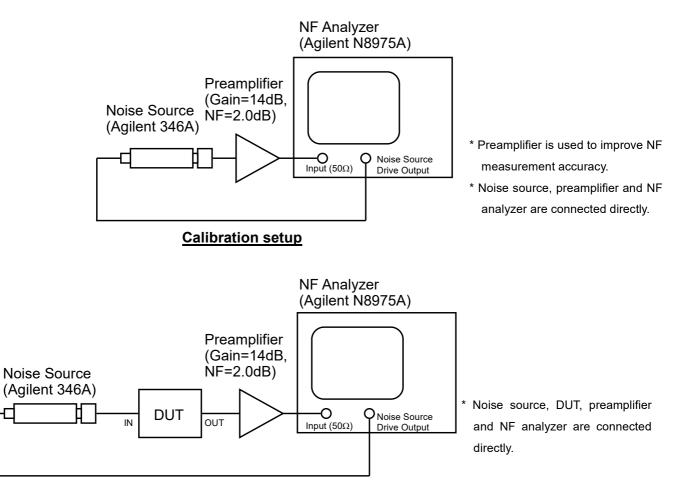
#### Measuring instruments

NF Analyzer	: Agilent N8975A
Noise Source	: Agilent 346A

#### Setting the NF analyzer

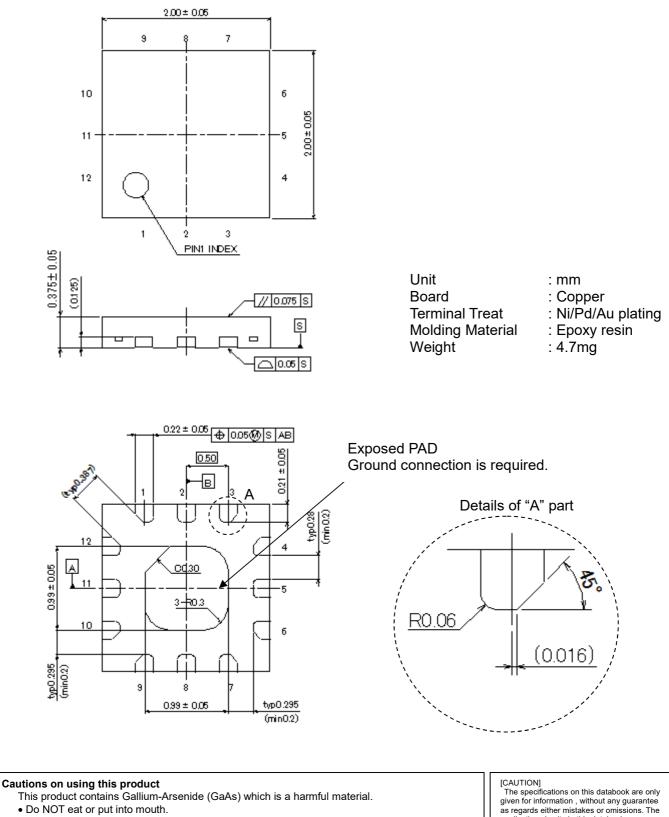
Measurement mode form	
Device under test	: Amplifier
System downconverter	: off
Mode setup form	
Sideband	: LSB
Averages	: 16
Average mode	: Point
Bandwidth	: 4MHz
Loss comp	: off
Tcold	: setting the tem

setting the temperature of noise source (303K)



Measurement Setup

#### ■ PACKAGE OUTLINE (QFN12-51)



- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

Nisshinbo Micro Devices Inc.

application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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  - Aerospace Equipment
  - Equipment Used in the Deep Sea
  - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
  - Life Maintenance Medical Equipment
  - Fire Alarms / Intruder Detectors
  - Vehicle Control Equipment (automotive, airplane, railroad, ship, etc.)
  - Various Safety Devices
  - Traffic control system
  - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
  - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

- Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
- 8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.

- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



Nisshinbo Micro Devices Inc.

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